

<b>Notice of References Cited</b>	Application/Control No. 10/822,648	Applicant(s)/Patent Under Reexamination CHEN ET AL.	
	Examiner Robert M. Kunemund	Art Unit 1722	Page 1 of 1

**U.S. PATENT DOCUMENTS**

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
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*	B	US-2005/0161662	07-2005	Majumdar et al.	257/018
*	C	US-2005/0009224	01-2005	Yang et al.	438/057
*	D	US-2005/0255629	11-2005	Han et al.	438/104
*	E	US-2003/0126742	07-2003	Ting et al.	29/874
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**NON-PATENT DOCUMENTS**

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
	U	Chiou et al., Growth of single crystal ZnO nanowires using sputter deposition", Science Direct, Diamond and related materials, vol.12 issue 10-11 oct-nov 2003, online 9/5/03
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\*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)  
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